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High Current Transistors

PNP Silicon

Features

• This is a Pb-Free Device



Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V _{CEO}	-80	Vdc
Collector-Base Voltage	V _{CBO}	-80	Vdc
Emitter-Base Voltage	V _{EBO}	-5.0	Vdc
Collector Current - Continuous	I _C	-0.5	Adc
Total Device Dissipation @ T _A = 25°C Derate above 25°C	P _D	625 5.0	mW mW/°C
Total Device Dissipation @ T _C = 25°C Derate above 25°C	P _D	1.5 12	W mW/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150	°C

THERMAL CHARACTERISTICS

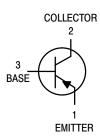
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	83.3	°C/W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



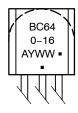
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MARKING DIAGRAMS



A = Assembly Location

Y = Year WW = Work Week

= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

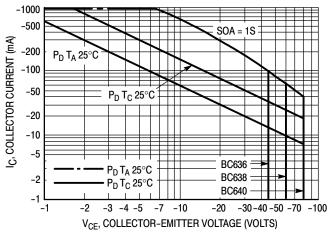
ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS	<u> </u>				
Collector – Emitter Breakdown Voltage ($I_C = -10$ mAdc, $I_B = 0$)	V _{(BR)CEO}	-80	-	-	Vdc
Collector – Base Breakdown Voltage ($I_C = -100 \mu Adc$, $I_E = 0$)	V _(BR) CBO	-80	-	-	Vdc
Emitter – Base Breakdown Voltage ($I_E = -10 \mu Adc, I_C = 0$)	V _{(BR)EBO}	-5.0	_	-	Vdc
Collector Cutoff Current $(V_{CB} = -30 \text{ Vdc}, I_E = 0)$ $(V_{CB} = -30 \text{ Vdc}, I_E = 0, T_A = 125^{\circ}\text{C})$	Ісво	- -	- -	-100 -10	nAdc μAdc
ON CHARACTERISTICS (Note 1)					
DC Current Gain ($I_C = -5.0$ mAdc, $V_{CE} = -2.0$ Vdc) ($I_C = -150$ mAdc, $V_{CE} = -2.0$ Vdc) ($I_C = -500$ mA, $V_{CE} = -2.0$ V)	h _{FE}	25 100 25	_ _ _	_ 250 _	_
Collector – Emitter Saturation Voltage (I _C = -500 mAdc, I _B = -50 mAdc)	V _{CE(sat)}	-	-0.25	-0.5	Vdc
Base – Emitter On Voltage (I _C = -500 mAdc, V _{CE} = -2.0 Vdc)	V _{BE(on)}	-	-	-1.0	Vdc
DYNAMIC CHARACTERISTICS					
Current Gain – Bandwidth Product ($I_C = -50$ mAdc, $V_{CE} = -2.0$ Vdc, $f = 100$ MHz)	f _T	-	150	-	MHz
Output Capacitance (V _{CB} = -10 Vdc, I _E = 0, f = 1.0 MHz)	C _{ob}	-	9.0	-	pF
Input Capacitance (V _{EB} = -0.5 Vdc, I _C = 0, f = 1.0 MHz)	C _{ib}	_	110	_	pF

^{1.} Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle 2.0%.

ORDERING INFORMATION

Device	Package	Shipping
BC640-016G	TO-92 (Pb-Free)	5000 Units / Bulk



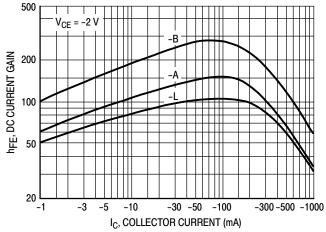
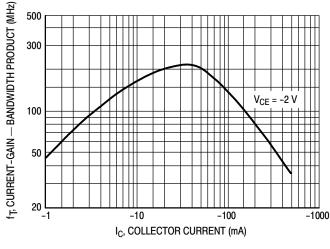


Figure 1. Active Region Safe Operating Area

Figure 2. DC Current Gain



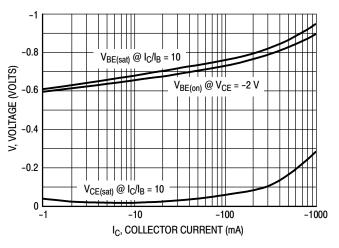


Figure 3. Current Gain Bandwidth Product

Figure 4. "Saturation" and "On" Voltages

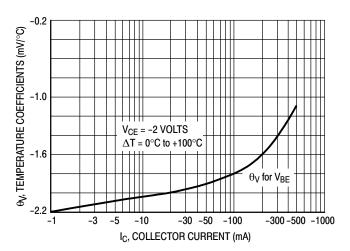
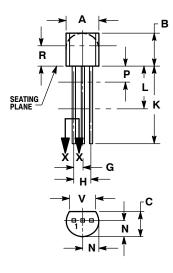


Figure 5. Temperature Coefficients

PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-11 **ISSUE AN**

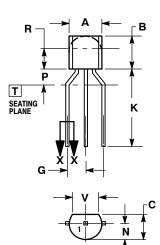


STRAIGHT LEAD **BULK PACK**



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- CONTOUR OF PACKAGE BEYOND DIMENSION R
- IS UNCONTROLLED.
 LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
P	-	0.100		2.54
R	0.115		2.93	
v	0 135		3 43	



BENT LEAD TAPE & REEL AMMO PACK



NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.

- CONTROLLING DIMENSION: MILLIMETERS.
 CONTOUR OF PACKAGE BEYOND
 DIMENSION R IS UNCONTROLLED.
 LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	MILLIMETERS		
DIM	MIN	MAX	
Α	4.45	5.20	
В	4.32	5.33	
С	3.18	4.19	
D	0.40	0.54	
G	2.40	2.80	
J	0.39	0.50	
K	12.70		
N	2.04	2.66	
P	1.50	4.00	
R	2.93		
٧	3.43		

STYLE 14:

PIN 1. EMITTER

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